

John C Thomas

List of Publications by Year in descending order

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29
papers

1,249
citations

471509
17
h-index

501196
28
g-index

31
all docs

31
docs citations

31
times ranked

1713
citing authors

#	ARTICLE	IF	CITATIONS
1	Nondilute diffusion from first principles: Li diffusion in $\text{Li}_{x\text{M}}^{(224)}$. <i>Physical Review B</i> , 2008, 78, .	3.2	224
2	Linking the electronic structure of solids to their thermodynamic and kinetic properties. <i>Mathematics and Computers in Simulation</i> , 2010, 80, 1393-1410.	4.4	160
3	Finite-temperature properties of strongly anharmonic and mechanically unstable crystal phases from first principles. <i>Physical Review B</i> , 2013, 88, .	3.2	138
4	Designing the next generation high capacity battery electrodes. <i>Energy and Environmental Science</i> , 2014, 7, 1760.	30.8	104
5	First-Principles Statistical Mechanics of Multicomponent Crystals. <i>Annual Review of Materials Research</i> , 2018, 48, 27-55.	9.3	98
6	Structural Order-Disorder Transitions and Phonon Conductivity of Partially Filled Skutterudites. <i>Physical Review Letters</i> , 2010, 105, 265901.	7.8	56
7	Low-temperature structural and transport anomalies in Cu ₂ Se. <i>Physical Review B</i> , 2014, 89, .	3.2	54
8	The exploration of nonlinear elasticity and its efficient parameterization for crystalline materials. <i>Journal of the Mechanics and Physics of Solids</i> , 2017, 107, 76-95.	4.8	36
9	Symmetry-adapted order parameters and free energies for solids undergoing order-disorder phase transitions. <i>Physical Review B</i> , 2017, 96, .	3.2	33
10	Configuring pnictogen rings in skutterudites for low phonon conductivity. <i>Physical Review B</i> , 2012, 86, .	3.2	30
11	PRISMS: An Integrated, Open-Source Framework for Accelerating Predictive Structural Materials Science. <i>Jom</i> , 2018, 70, 2298-2314.	1.9	30
12	Finite-temperature simulation of anharmonicity and octahedral tilting transitions in halide perovskites. <i>Physical Review Materials</i> , 2019, 3, .	2.4	28
13	Surface structure of bismuth terminated GaAs surfaces grown with molecular beam epitaxy. <i>Surface Science</i> , 2012, 606, 1203-1207.	1.9	27
14	Systematic approach for determination of equilibrium atomic surface structure. <i>Physical Review B</i> , 2010, 82, .	3.2	24
15	Elastic properties and stress-temperature phase diagrams of high-temperature phases with low-temperature lattice instabilities. <i>Physical Review B</i> , 2014, 90, .	3.2	23
16	Surface reconstruction stability and configurational disorder on Bi-terminated GaAs(001). <i>Physical Review B</i> , 2013, 87, .	3.2	22
17	Comparing crystal structures with symmetry and geometry. <i>Npj Computational Materials</i> , 2021, 7, .	8.7	21
18	Effects of strain on the stability of tetragonal ZrO ₂ . <i>Physical Review B</i> , 2016, 94, .	18	18

#	ARTICLE	IF	CITATIONS
19	Order-disorder versus displacive transitions in Jahn-Teller active layered materials. Physical Review Materials, 2020, 4, .	2.4	17
20	Machine learning the density functional theory potential energy surface for the inorganic halide perovskite CsPbBr_3 . Physical Review B, 2019, 100, .	3.2	14
21	Integrated Computational Modeling of Water Side Corrosion in Zirconium Metal Clad Under Nominal LWR Operating Conditions. Jom, 2016, 68, 2900-2911.	1.9	13
22	Order parameters for symmetry-breaking structural transitions: The tetragonal-monoclinic transition in ZrO_2 . Physical Review B, 2017, 96, .	3.2	12
23	Surface atomic order of compound III-V semiconductor alloys at finite temperature. Physical Review B, 2009, 80, .	3.2	10
24	Hamiltonians and order parameters for crystals of orientable molecules. Physical Review B, 2018, 98, .	3.2	9
25	Discovering hierarchies among intermetallic crystal structures. Physical Review Materials, 2020, 4, .	2.4	9
26	Considerations for surface reconstruction stability prediction on GaAs(001). Physical Review B, 2013, 87, .	3.2	8
27	First-principles survey of the structure, formation energies, and transition levels of As-interstitial defects in InGaAs. Physical Review B, 2015, 92, .	3.2	7
28	Bismuth-containing III-V semiconductors. , 2013, , 139-158.		6
29	Phase stability analysis of the InAs/GaAs (001) wetting layer from first principles. Physical Review B, 2014, 89, .	3.2	1